



# Automotive LPDDR5/LPDDR5X SDRAM

**MT62F768M32D2, MT62F1536M32D4, MT62F3G32D8**

## Features

- **Architecture**
  - 17.1 GB/s maximum bandwidth per channel
  - Frequency range: 1067–5 MHz (data rate range per pin: 8533–40 Mb/s with WCK:CK = 4:1)
  - Selectable CKR (WCK:CK = 2:1 or 4:1)
- **LPDDR5X data interface**
  - Single x16 channel/die
  - Double-data-rate command/address entry
  - Differential command clocks (CK<sub>t</sub>/CK<sub>c</sub>) for high-speed operation
  - Differential data clocks (WCK<sub>t</sub>/WCK<sub>c</sub>)
  - Differential read strobe (RDQS<sub>t</sub>/RDQS<sub>c</sub>)
  - 16n-bit or 32n-bit prefetch architecture
  - Command-selectable burst lengths (BL = 16 or 32) in bank group or 16-bank modes
  - Background ZQ calibration/command-based ZQ calibration
  - Link protection (link ECC) support
  - Partial-array self refresh (PASR) and partial-array auto refresh (PAAR) with segment mask
- **Ultra-low-voltage core and I/O power supplies**
  - V<sub>DD1</sub> = 1.70–1.95V; 1.80V TYP
  - V<sub>DD2H</sub> = 1.01–1.12V; 1.05V TYP
  - V<sub>DD2L</sub> = V<sub>DD2H</sub> or 0.87–0.97V; 0.90V TYP
  - V<sub>DDQ</sub> = 0.50V TYP or 0.30V TYP (ODT off only)
- **I/O characteristics**
  - Interface-LVSTL 0.5/0.3
  - I/O type: Low-swing single-ended, V<sub>SS</sub> terminated
  - V<sub>OH</sub>-compensated output drive
  - Programmable V<sub>SS</sub> on-die termination (ODT)
  - Non target ODT support
  - DVFSQ support
- **Low-power features**
  - DVFSC: Dynamic voltage frequency scaling core
  - Single-ended CK, single-ended WCK, and single-ended RDQS
  - Data copy
  - Write X

## Options

- **Operating Voltage**
  - V<sub>DD1</sub>/V<sub>DD2H</sub>/V<sub>DD2L</sub>/V<sub>DDQ</sub>/V<sub>DDQ</sub>(ODT off only): 1.8V/1.05V/0.9V/0.5V/0.3V
- **Array configuration**
  - 768 Meg x 32 (768M16 x 2Ch x 1R)
  - 1536 Meg x 32 (768M16 x 2Ch x 2R)
  - 3 Gig x 32 (1536M16 x 2Ch x 2R)
- **Device configuration**
  - 2 die in package (768M16 x 2 die)
  - 4 die in package (768M16 x 4 die)
  - 8 die in package (1536M8 x 8 die)
- **FBGA RoHS-compliant, "green" package**
  - 315-ball TFBGA  
12.4mm x 15.0mm (TYP)  
Seated height 1.1mm (MAX)
  - 315-ball LFBGA  
12.4mm x 15.0mm (TYP)  
Seated height 1.3mm (MAX)
- **Speed grade, cycle time (<sup>t</sup>WCK)**
  - 8533 Mb/s
  - 7500 Mb/s
- **Functional safety features**
  - Micron safety features enabled
  - Suitable for meeting random HW metrics up to ASIL D
- **Automotive and functional safety**
- **Operating temperature**
- **Revision**

## Marking

F

768M32  
1536M32  
3G32

D2  
D4  
D8

DS

DV

-023  
-026

F

A<sup>1</sup>

IT  
AT  
UT<sup>2</sup>  
:B

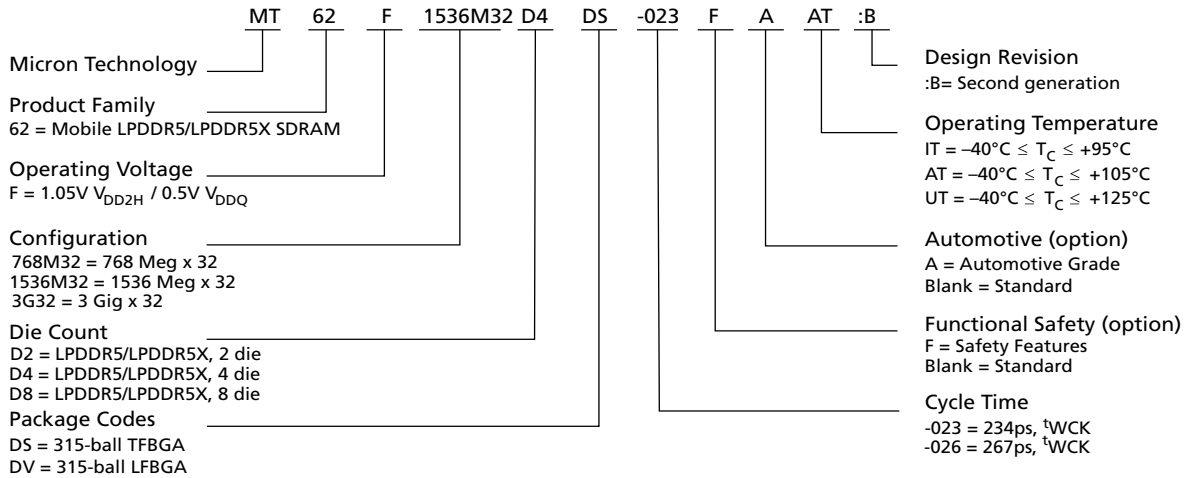
- Notes: 1. For functional safety documentation, contact a Micron sales representative.
2. Based on automotive usage model. Contact a Micron sales representative with questions.



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Part Number Ordering Information

### Part Number Ordering Information

**Figure 1: Part Number Chart**



**Table 1: Part Number List**

| Part Number                 | Total Density | Data Rate per Pin |
|-----------------------------|---------------|-------------------|
| MT62F768M32D2DS-023 AIT:B   | 3GB (24Gb)    | 8533 Mb/s         |
| MT62F768M32D2DS-023 AAT:B   |               |                   |
| MT62F768M32D2DS-023 AUT:B   |               |                   |
| MT62F768M32D2DS-023 FAAT:B  |               |                   |
| MT62F1536M32D4DS-023 AIT:B  | 6GB (48Gb)    |                   |
| MT62F1536M32D4DS-023 AAT:B  |               |                   |
| MT62F1536M32D4DS-023 AUT:B  |               |                   |
| MT62F1536M32D4DS-023 FAAT:B |               |                   |
| MT62F3G32D8DV-023 AIT:B     | 12GB (96Gb)   |                   |
| MT62F3G32D8DV-023 AAT:B     |               |                   |
| MT62F3G32D8DV-023 AUT:B     |               |                   |
| MT62F3G32D8DV-023 FAAT:B    |               |                   |
| MT62F1536M32D4DS-026 AIT:B  | 6GB (48Gb)    | 7500 Mb/s         |
| MT62F1536M32D4DS-026 AAT:B  |               |                   |
| MT62F3G32D8DV-026 AIT:B     | 12GB (96Gb)   |                   |
| MT62F3G32D8DV-026 AAT:B     |               |                   |

### FBGA Part Marking Decoder

Due to space limitations, FBGA-packaged components have an abbreviated part marking that is different from the part number. Micron's FBGA part marking decoder is available at [www.micron.com/decoder](http://www.micron.com/decoder).



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Part Number Ordering Information

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### LPDDR5/LPDDR5X Data Sheet List

This data sheet only describes the product specifications that are unique to the Micron devices listed in Table 1.

For general LPDDR5/LPDDR5X specifications, please refer to the data sheets below.

- General LPDDR5/LPDDR5X Specifications 1: Mode Registers
- General LPDDR5/LPDDR5X Specifications 2: AC/DC and Interface Specifications
- General LPDDR5/LPDDR5X Specifications 3: Features and Functionalities



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM

### Contents

|                                                 |    |
|-------------------------------------------------|----|
| Part Number Ordering Information .....          | 2  |
| FBGA Part Marking Decoder .....                 | 2  |
| LPDDR5/LPDDR5X Data Sheet List .....            | 3  |
| Important Notes and Warnings .....              | 7  |
| General Notes .....                             | 8  |
| Functional Safety Notes .....                   | 9  |
| Device Configuration .....                      | 10 |
| Refresh Requirement Parameters .....            | 11 |
| Package Block Diagrams .....                    | 12 |
| Dual Die, Dual Channel, Single Rank .....       | 12 |
| Quad Die, Dual Channel, Dual Rank .....         | 13 |
| Eight Die, Dual Channel, Dual Rank .....        | 14 |
| 315b Dual Channel, 1 Rank, 2 Rank .....         | 15 |
| Package Dimensions .....                        | 17 |
| 315-Ball Package (Package Code: DS) .....       | 17 |
| 315-Ball Package (Package Code: DV) .....       | 18 |
| Product-Specific Mode Register Definition ..... | 19 |
| I <sub>DD</sub> Parameters .....                | 21 |
| Revision History .....                          | 27 |
| Rev. C – 06/2022 .....                          | 27 |
| Rev. B – 04/2022 .....                          | 27 |
| Rev. A .....                                    | 27 |



315b: x32 Automotive LPDDR5/LPDDR5X SDRAM

List of Figures

Figure 1: Part Number Chart. . . . . 2

Figure 2: Dual Die, Dual Channel, Single Rank Package Block Diagram . . . . . 12

Figure 3: Quad Die, Dual Channel, Dual Rank Package Block Diagram . . . . . 13

Figure 4: Eight Die, Dual Channel, Dual Rank Package Block Diagram . . . . . 14

Figure 5: 315-Ball Dual-Channel Discrete FBGA . . . . . 16

Figure 6: 315-Ball TFBGA – 12.4mm (TYP) x 15.0mm (TYP) x 1.1mm (MAX) . . . . . 17

Figure 7: 315-Ball LFBGA – 12.4mm (TYP) x 15.0mm (TYP) x 1.3mm (MAX) . . . . . 18



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM

### List of Tables

|                                                                       |    |
|-----------------------------------------------------------------------|----|
| Table 1: Part Number List .....                                       | 2  |
| Table 2: Die Organization in the Package .....                        | 10 |
| Table 3: Die Addressing .....                                         | 10 |
| Table 4: Refresh Requirement Parameters .....                         | 11 |
| Table 5: 315-Ball/Pad Descriptions.....                               | 15 |
| Table 6: Mode Register Contents.....                                  | 19 |
| Table 7: $I_{DD}$ Parameters at 7500 Mb/s – Single Die .....          | 21 |
| Table 8: $I_{DD}$ Parameters at 8533 Mb/s – Single Die .....          | 23 |
| Table 9: Full-Array Power-Down Self Refresh Current – Single Die..... | 25 |



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Important Notes and Warnings

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## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM General Notes

### General Notes

Throughout the data sheet, figures and text refer to DQs as DQ. DQ should be interpreted as any or all DQs collectively, unless specifically stated otherwise.

RDQS, CK, and WCK should be interpreted as RDQS\_t, RDQS\_c, CK\_t, CK\_c, and WCK\_t, WCK\_c respectively unless specifically stated otherwise. CA includes all CA pins used for a given density.

In timing diagrams, CMD is used as an indicator only. Actual signals occur on CA[6:0].

$V_{REF}$  indicates  $V_{REF(CA)}$  and  $V_{REF(DQ)}$ .

Complete functionality is described throughout the entire document. Any page or diagram may have been simplified to convey a topic and may not be inclusive of all requirements.

Any specific requirement takes precedence over a general statement.

Any functionality not specifically stated herein is considered undefined, illegal, is not supported, and will result in unknown operation.



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Functional Safety Notes

### Functional Safety Notes

This automotive LPDDR5/LPDDR5X DRAM product family has been developed according to ISO 26262:2018 requirements to provide a level of systematic fault coverage that allows its use in systems targeting up to ASIL D compliance.

This LPDDR5/LPDDR5X DRAM contains several new functional safety features that operate within the JEDEC LPDDR5/LPDDR5X protocols (commands, timings, and so forth) and are made available to the integrator on “F” parts (see Part Number Ordering Information). The specification addendum governing these functional safety features is available under NDA. This LPDDR5/LPDDR5X DRAM may operate as a standard JEDEC LPDDR5/LPDDR5X DRAM only, or as a standard JEDEC LPDDR5/LPDDR5X DRAM specifically designed to include functional safety features to communicate fault detection (only available on “F” parts). Additional support may be available to customers who need to integrate Micron’s products in their functional safety-related applications. This support may include Safety Analysis Report, reporting FMEDA results and metrics, Safety Manual and Pin FMEA Report, providing guidelines and instructions for using Micron products in safety-related applications.

Contact a Micron sales representative to initiate the process required to obtain the functional safety documentation.



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Device Configuration

### Device Configuration

**Table 2: Die Organization in the Package**

| Die Organization            | 768M32 (24 Gb/package) | 1536M32 (48 Gb/package) | 3G32 (96 Gb/package) |
|-----------------------------|------------------------|-------------------------|----------------------|
| Channel A                   | x16 mode × 1 die       | –                       | –                    |
| Channel B                   | x16 mode × 1 die       | –                       | –                    |
| Channel A, rank 0           | –                      | x16 mode × 1 die        | –                    |
| Channel B, rank 0           | –                      | x16 mode × 1 die        | –                    |
| Channel A, rank 1           | –                      | x16 mode × 1 die        | –                    |
| Channel B, rank 1           | –                      | x16 mode × 1 die        | –                    |
| Channel A, rank 0, DQ[7:0]  | –                      | –                       | x8 mode × 1 die      |
| Channel A, rank 1, DQ[7:0]  | –                      | –                       | x8 mode × 1 die      |
| Channel B, rank 0, DQ[7:0]  | –                      | –                       | x8 mode × 1 die      |
| Channel B, rank 1, DQ[7:0]  | –                      | –                       | x8 mode × 1 die      |
| Channel A, rank 0, DQ[15:8] | –                      | –                       | x8 mode × 1 die      |
| Channel A, rank 1, DQ[15:8] | –                      | –                       | x8 mode × 1 die      |
| Channel B, rank 0, DQ[15:8] | –                      | –                       | x8 mode × 1 die      |
| Channel B, rank 1, DQ[15:8] | –                      | –                       | x8 mode × 1 die      |

Note: 1. Refer to the Package Block Diagram section in this data sheet.

**Table 3: Die Addressing**

| Description           | 768M32 (24Gb/package), 1536M32 (48Gb/package) |                         |                        | 3G32 (96 Gb/package)        |                        |                        |
|-----------------------|-----------------------------------------------|-------------------------|------------------------|-----------------------------|------------------------|------------------------|
| Density per die       | 12Gb                                          |                         |                        | 12Gb                        |                        |                        |
| Bits                  | 12,884,901,888                                |                         |                        | 12,884,901,888              |                        |                        |
| Bank mode             | BG mode                                       | 16B mode                | 8B mode                | BG mode                     | 16B mode               | 8B mode                |
| Configuration         | 48Mb × 16 DQ × 4 banks × 4BG                  | 48Mb × 16 DQ × 16 banks | 96Mb × 16 DQ × 8 banks | 96Mb × 8 DQ × 4 banks × 4BG | 96Mb × 8 DQ × 16 banks | 192Mb × 8 DQ × 8 banks |
| Number of banks       | 4                                             | 16                      | 8                      | 4                           | 16                     | 8                      |
| Number of bank groups | 4                                             | 1                       | 1                      | 4                           | 1                      | 1                      |
| Array prefetch bits   | 256                                           | 256                     | 512                    | 128                         | 128                    | 256                    |
| Rows per bank         | 49,152                                        |                         |                        | 98,304                      |                        |                        |
| Columns               | 64                                            |                         |                        | 64                          |                        |                        |
| Page size (bytes)     | 2048                                          | 2048                    | 4096                   | 1024                        | 1024                   | 2048                   |
| Native burst length   | 16                                            | 16                      | 32                     | 16                          | 16                     | 32                     |
| Number of I/Os        | 16                                            |                         |                        | 8                           |                        |                        |



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Refresh Requirement Parameters

**Table 3: Die Addressing (Continued)**

| Description                     | 768M32 (24Gb/package), 1536M32 (48Gb/package) |         |         | 3G32 (96 Gb/package)           |         |         |
|---------------------------------|-----------------------------------------------|---------|---------|--------------------------------|---------|---------|
|                                 | BA[1:0]                                       | BA[3:0] | BA[2:0] | BA[1:0]                        | BA[3:0] | BA[2:0] |
| Bank address                    | BA[1:0]                                       | BA[3:0] | BA[2:0] | BA[1:0]                        | BA[3:0] | BA[2:0] |
| Bank group address              | BG[1:0]                                       | –       | –       | BG[1:0]                        | –       | –       |
| Row address                     | R[15:0] (R14 = 0 when R15 = 1)                |         |         | R[16:0] (R15 = 0 when R16 = 1) |         |         |
| Column address                  | C[5:0]                                        |         |         | C[5:0]                         |         |         |
| Burst address                   | B[3:0]                                        | B[3:0]  | B[4:0]  | B[3:0]                         | B[3:0]  | B[4:0]  |
| Burst starting address boundary | 128-bit                                       |         |         | 128-bit                        |         |         |

- Notes: 1. Refer to the SDRAM Addressing section in General LPDDR5/LPDDR5X Specifications 3.  
2. Refer to the Speed Grades and Effective Burst Length in General LPDDR5/LPDDR5X Specifications 3.

## Refresh Requirement Parameters

**Table 4: Refresh Requirement Parameters**

| Parameter                                                  | Symbol        | 12Gb Die        |         | Unit |
|------------------------------------------------------------|---------------|-----------------|---------|------|
|                                                            |               | BG and 16B Mode | 8B Mode |      |
| REFRESH cycle time (all banks)                             | $t_{RFCab}$   | 280             | 280     | ns   |
| REFRESH cycle time (per bank)                              | $t_{RFCpb}$   | 140             | 140     | ns   |
| Per bank refresh to per bank refresh time (different bank) | $t_{PBR2PBR}$ | 90              | 90      | ns   |
| Per bank refresh to ACTIVATE command time (different bank) | $t_{PBR2ACT}$ | 7.5             | 10      | ns   |

- Note: 1. This table only describes refresh parameters that are density dependent. Refer to Refresh Requirement section in General LPDDR5/LPDDR5X Specifications 3 for all refresh parameters.

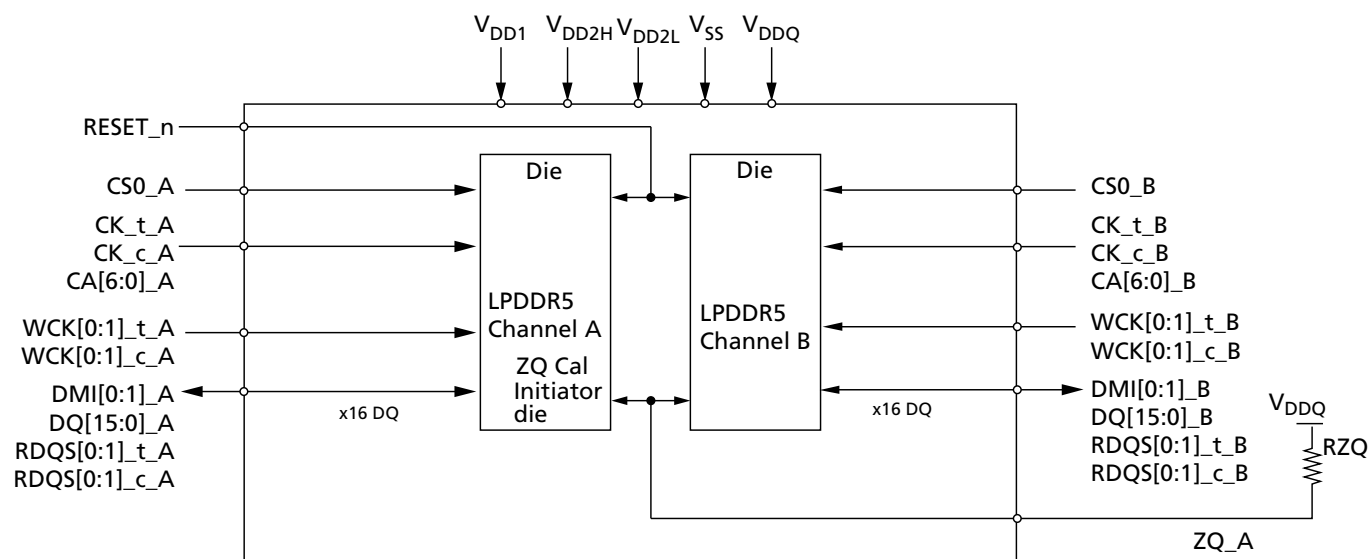


## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Package Block Diagrams

### Package Block Diagrams

#### Dual Die, Dual Channel, Single Rank

Figure 2: Dual Die, Dual Channel, Single Rank Package Block Diagram

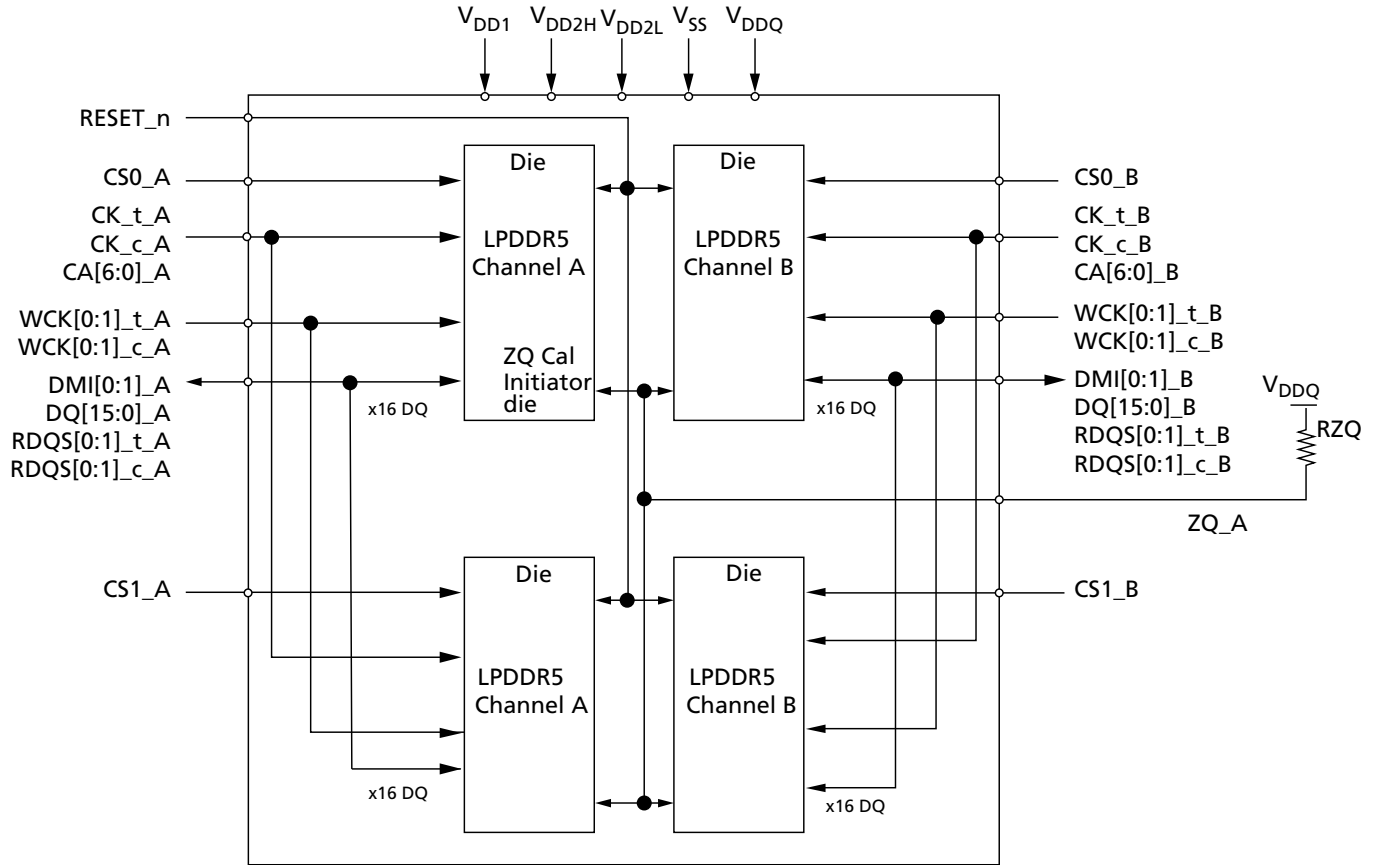




## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Package Block Diagrams

### Quad Die, Dual Channel, Dual Rank

Figure 3: Quad Die, Dual Channel, Dual Rank Package Block Diagram

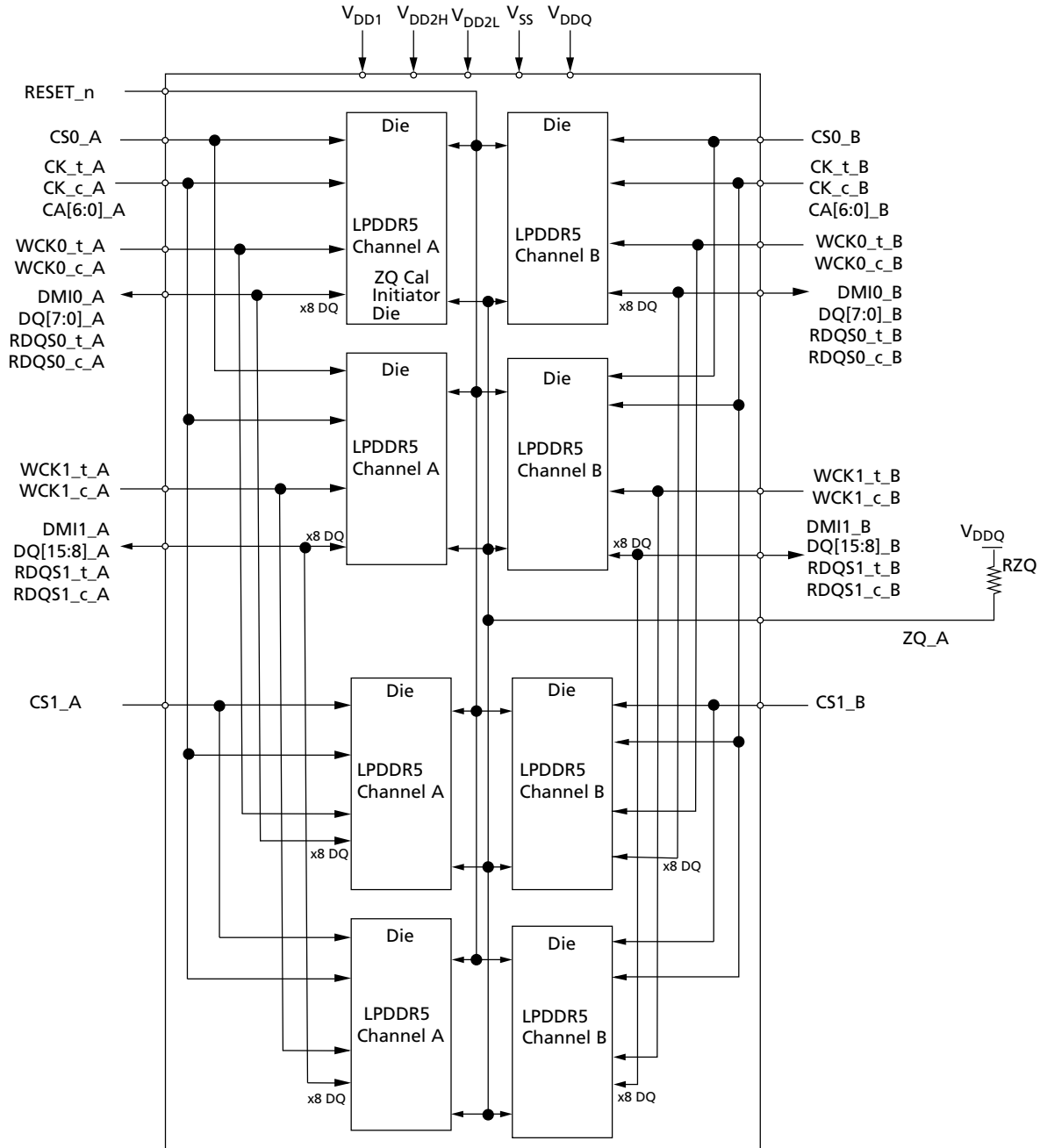




## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Package Block Diagrams

### Eight Die, Dual Channel, Dual Rank

Figure 4: Eight Die, Dual Channel, Dual Rank Package Block Diagram





## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM

### 315b Dual Channel, 1 Rank, 2 Rank

## 315b Dual Channel, 1 Rank, 2 Rank

**Table 5: 315-Ball/Pad Descriptions**

| Symbol                                                                         | Type          | Description                                                                                                                                                                                                                                                                                                                                                                                                                     |
|--------------------------------------------------------------------------------|---------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| CK_t_[A:B],<br>CK_c_[A:B]                                                      | Input         | <b>Clock:</b> CK_t and CK_c are differential clock inputs. All double data rate (DDR) command/address inputs are sampled on both crossing points of CK_t and CK_c. The first crossing point is the rising (falling) edge of CK_t (CK_c) and second crossing point is falling (rising) edge of CK_t (CK_c). Single data rate (SDR) inputs, CS is sampled on the crossing point that is the rising (falling) edge of CK_t (CK_c). |
| CS0_[A:B], CS1_[A:B]                                                           | Input         | <b>Chip select:</b> CS is part of the command code, and is sampled on the rising (falling) edge of CK_t (CK_c) unless the device is in power-down or deep sleep mode where it becomes an asynchronous signal. Each rank (0, 1) has its own CS signals. CS1_[A:B] become NC pins in a single-rank package.                                                                                                                       |
| CA[6:0]_[A:B]                                                                  | Input         | <b>Command/address inputs:</b> Provide the command and address inputs according to the command truth table.                                                                                                                                                                                                                                                                                                                     |
| WCK[1:0]_t_[A:B],<br>WCK[1:0]_c_[A:B]                                          | Input         | <b>Data clock:</b> WCK_t and WCK_c are differential clock inputs used for write data capture and read data output.                                                                                                                                                                                                                                                                                                              |
| DQ[15:0]_[A:B]                                                                 | I/O           | <b>Data input/output:</b> Bidirectional data bus.                                                                                                                                                                                                                                                                                                                                                                               |
| RDQS[1:0]_t_[A:B],<br>RDQS[1:0]_c_[A:B]                                        | I/O<br>Output | <b>Read data strobe:</b> RDQS_t and RDQS_c are differential output clock signals used to strobe data during a READ operation. RDQS_t is also used as a parity pin during write link protection enabled. Each byte of data has RDQS_t and RDQS_c signals.                                                                                                                                                                        |
| DMI[1:0]_[A:B]                                                                 | I/O           | <b>Data mask inversion:</b> DMI serves multiple functions such as data mask (DM), data bus inversion (DBI), and parity at READ with ECC operation by setting the mode register. DMI is a bidirectional signal and each byte of data has a DMI signal.                                                                                                                                                                           |
| ZQ_A                                                                           | Reference     | <b>ZQ calibration reference:</b> Used to calibrate the output drive strength and the termination resistance. The ZQ pin should be connected to V <sub>DDQ</sub> through a 240Ω ±1% resistor.                                                                                                                                                                                                                                    |
| V <sub>DDQ</sub> , V <sub>DD1</sub> , V <sub>DD2H</sub> ,<br>V <sub>DD2L</sub> | Supply        | <b>Power supplies:</b> Isolated on the die for improved noise immunity.                                                                                                                                                                                                                                                                                                                                                         |
| V <sub>SS</sub>                                                                | Supply        | <b>Ground reference:</b> Power supply ground reference.                                                                                                                                                                                                                                                                                                                                                                         |
| RESET_n                                                                        | Input         | <b>Reset:</b> When asserted LOW, the RESET pin resets the die. Reset is an asynchronous signal.                                                                                                                                                                                                                                                                                                                                 |
| NC                                                                             | –             | <b>No connect:</b> Not internally connected.                                                                                                                                                                                                                                                                                                                                                                                    |
| RFU                                                                            | –             | <b>Reserved Future Use:</b> Not internally connected.                                                                                                                                                                                                                                                                                                                                                                           |



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM

### 315b Dual Channel, 1 Rank, 2 Rank

**Figure 5: 315-Ball Dual-Channel Discrete FBGA**

|    | 1                 | 2                 | 3                 | 4                 | 5                 | 6                 | 7                 | 8                 | 9                 | 10                | 11                | 12                | 13                | 14                | 15                |    |
|----|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|----|
| A  | NC                | NC                | V <sub>DDQ</sub>  | DMI0_A            | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2L</sub> | V <sub>SS</sub>   | DMI1_A            | V <sub>DDQ</sub>  | NC                | NC                | A  |
| B  | NC                | V <sub>DDQ</sub>  | RDQS0_t_A         | V <sub>SS</sub>   | DQ4_A             | V <sub>DD2L</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2L</sub> | DQ12_A            | V <sub>SS</sub>   | RDQS1_t_A         | V <sub>DDQ</sub>  | NC                | B  |
| C  | V <sub>DD1</sub>  | DQ1_A             | V <sub>DDQ</sub>  | RDQS0_c_A         | V <sub>SS</sub>   | DQ5_A             | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | DQ13_A            | V <sub>SS</sub>   | RDQS1_c_A         | V <sub>DDQ</sub>  | DQ9_A             | V <sub>DD1</sub>  | C  |
| D  | DQ0_A             | V <sub>SS</sub>   | DQ3_A             | V <sub>DDQ</sub>  | WCK0_c_A          | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | WCK1_c_A          | V <sub>DDQ</sub>  | DQ11_A            | V <sub>SS</sub>   | DQ8_A             | D  |
| E  | V <sub>SS</sub>   | DQ2_A             | V <sub>SS</sub>   | WCK0_t_A          | V <sub>DDQ</sub>  | DQ6_A             | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | DQ14_A            | V <sub>DDQ</sub>  | WCK1_t_A          | V <sub>SS</sub>   | DQ10_A            | V <sub>SS</sub>   | E  |
| F  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | DQ7_A             | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2H</sub> | DQ15_A            | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | V <sub>DDQ</sub>  | F  |
| G  | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | CA0_A             | V <sub>SS</sub>   | CS1_A             | V <sub>SS</sub>   | CA2_A             | V <sub>SS</sub>   | CA4_A             | V <sub>SS</sub>   | CA6_A             | V <sub>SS</sub>   | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | G  |
| H  | RESET_N           | V <sub>DD2L</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | CA1_A             | V <sub>SS</sub>   | CS0_A             | V <sub>SS</sub>   | CK_t_A            | V <sub>SS</sub>   | CA3_A             | V <sub>SS</sub>   | CA5_A             | V <sub>DD2L</sub> | ZQ_A              | H  |
| J  | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>SS</sub>   | RFU               | V <sub>DD2H</sub> | RFU               | V <sub>SS</sub>   | V <sub>SS</sub>   | CK_c_A            | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>SS</sub>   | J  |
| K  | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | K  |
| L  | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | L  |
| M  | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | M  |
| N  | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>SS</sub>   | CK_c_B            | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>SS</sub>   | N  |
| P  | RFU               | V <sub>DD2L</sub> | CA5_B             | V <sub>SS</sub>   | CA3_B             | V <sub>SS</sub>   | CK_t_B            | V <sub>SS</sub>   | CS0_B             | V <sub>SS</sub>   | CA1_B             | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2L</sub> | RFU               | P  |
| R  | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | CA6_B             | V <sub>SS</sub>   | CA4_B             | V <sub>SS</sub>   | CA2_B             | V <sub>SS</sub>   | CS1_B             | V <sub>SS</sub>   | CA0_B             | V <sub>SS</sub>   | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | R  |
| T  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | DQ15_B            | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2H</sub> | DQ7_B             | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | V <sub>DDQ</sub>  | T  |
| U  | V <sub>SS</sub>   | DQ10_B            | V <sub>SS</sub>   | WCK1_t_B          | V <sub>DDQ</sub>  | DQ14_B            | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | DQ6_B             | V <sub>DDQ</sub>  | WCK0_t_B          | V <sub>SS</sub>   | DQ2_B             | V <sub>SS</sub>   | U  |
| V  | DQ8_B             | V <sub>SS</sub>   | DQ11_B            | V <sub>DDQ</sub>  | WCK1_c_B          | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | WCK0_c_B          | V <sub>DDQ</sub>  | DQ3_B             | V <sub>SS</sub>   | DQ0_B             | V  |
| W  | V <sub>DD1</sub>  | DQ9_B             | V <sub>DDQ</sub>  | RDQS1_c_B         | V <sub>SS</sub>   | DQ13_B            | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | DQ5_B             | V <sub>SS</sub>   | RDQS0_c_B         | V <sub>DDQ</sub>  | DQ1_B             | V <sub>DD1</sub>  | W  |
| Y  | NC                | V <sub>DDQ</sub>  | RDQS1_t_B         | V <sub>SS</sub>   | DQ12_B            | V <sub>DD2L</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2L</sub> | DQ4_B             | V <sub>SS</sub>   | RDQS0_t_B         | V <sub>DDQ</sub>  | NC                | Y  |
| AA | NC                | NC                | V <sub>DDQ</sub>  | DMI1_B            | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2L</sub> | V <sub>SS</sub>   | DMI0_B            | V <sub>DDQ</sub>  | NC                | NC                | AA |
|    | 1                 | 2                 | 3                 | 4                 | 5                 | 6                 | 7                 | 8                 | 9                 | 10                | 11                | 12                | 13                | 14                | 15                |    |

Top View (ball down)

V<sub>SS</sub>
V<sub>DD1</sub>
V<sub>DD2H</sub>
V<sub>DD2L</sub>
V<sub>DDQ</sub>
CK
RDQS
WCK
DQ, DMI
CA, CS, ZQ, RESET
NC, RFU

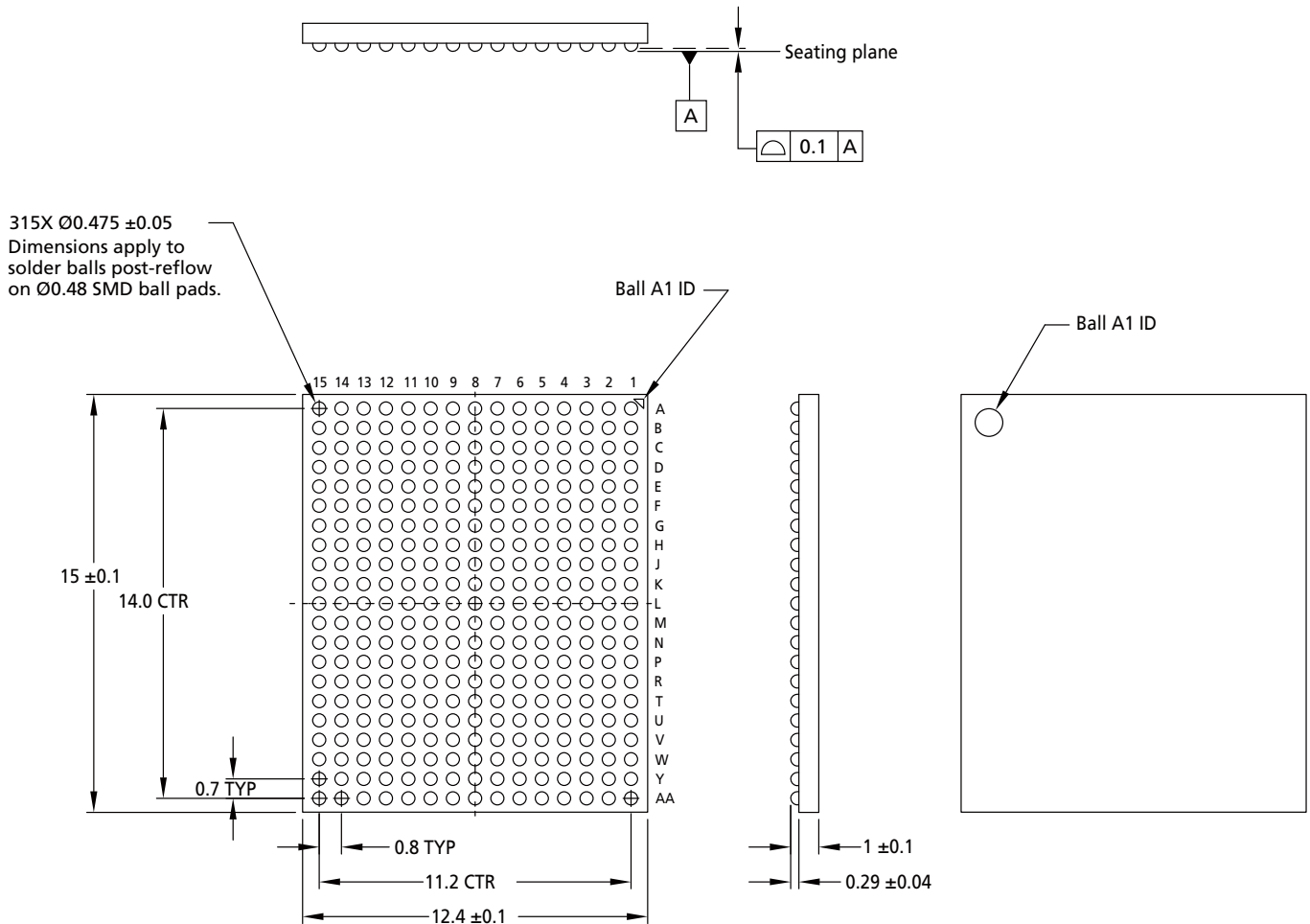


## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Package Dimensions

### Package Dimensions

#### 315-Ball Package (Package Code: DS)

**Figure 6: 315-Ball TFBGA – 12.4mm (TYP) x 15.0mm (TYP) x 1.1mm (MAX)**



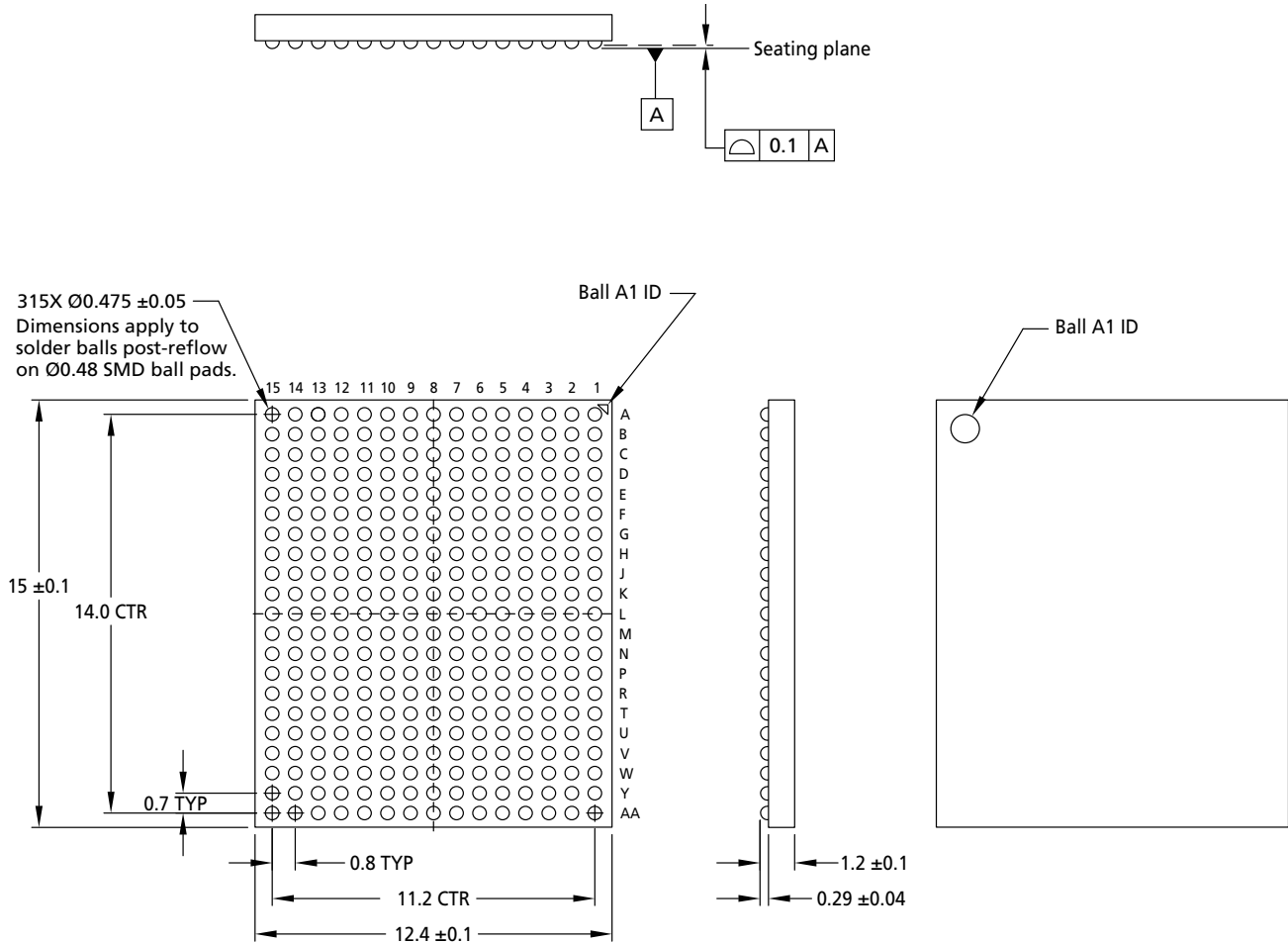
- Notes: 1. All dimensions are in millimeters.  
2. Solder ball composition: SACQ with CuOSP pads (Sn-4Ag-0.5Cu-3Bi-0.05Ni)



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Package Dimensions

### 315-Ball Package (Package Code: DV)

**Figure 7: 315-Ball LFBGA – 12.4mm (TYP) x 15.0mm (TYP) x 1.3mm (MAX)**



- Notes: 1. All dimensions are in millimeters.  
2. Solder ball composition: SACQ with CuOSP pads (Sn-4Ag-0.5Cu-3Bi-0.05Ni)



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Product-Specific Mode Register Definition

### Product-Specific Mode Register Definition

**Table 6: Mode Register Contents**

| Mode Register | OP7                                                                                                                              | OP6          | OP5                          | OP4                      | OP3                    | OP2                         | OP1                          | OP0                |
|---------------|----------------------------------------------------------------------------------------------------------------------------------|--------------|------------------------------|--------------------------|------------------------|-----------------------------|------------------------------|--------------------|
| MR0           | Per-pin DFE                                                                                                                      | Pre Emphasis | Unified NT ODT behavior mode | DMI output behavior mode | Optimized refresh mode | Enhanced WCK always-on mode | Latency mode                 | NT ODT timing mode |
|               | OP[0] = 1b: Device supports different NT ODT latency for DQ and RDQS                                                             |              |                              |                          |                        |                             |                              |                    |
|               | OP[1] = 0b: Device supports x16 mode latency for 768M32, 1536M32<br>OP[1] = 1b: Device supports x8 mode latency for 3G32         |              |                              |                          |                        |                             |                              |                    |
|               | OP[2] = 1b: Device supports enhanced WCK always-on mode                                                                          |              |                              |                          |                        |                             |                              |                    |
|               | OP[3] = 1b: Device supports optimized refresh mode                                                                               |              |                              |                          |                        |                             |                              |                    |
|               | OP[4] = 1b: Device supports both DMI behavior mode 1 and 2 and mode selection                                                    |              |                              |                          |                        |                             |                              |                    |
|               | OP[5] = 1b: The NT ODT behavior follows the unified NT ODT behavior                                                              |              |                              |                          |                        |                             |                              |                    |
|               | OP[6] = 1b: Device supports Pre Emphasis mode                                                                                    |              |                              |                          |                        |                             |                              |                    |
|               | OP[7] = 0b: Device does not support Per Pin DFE                                                                                  |              |                              |                          |                        |                             |                              |                    |
| MR1           |                                                                                                                                  |              |                              |                          |                        |                             | ARFM support <sup>3</sup>    | CS ODT OP support  |
|               | OP[0] = 0b: Device does not support CS ODT behavior OP                                                                           |              |                              |                          |                        |                             |                              |                    |
|               | OP[1] = 0b: Device does not support ARFM                                                                                         |              |                              |                          |                        |                             |                              |                    |
| MR3           |                                                                                                                                  |              |                              | BK/BG Org                |                        |                             |                              |                    |
|               | OP[4:3] = 00b: BG, 01b: 8B, 10b: 16B Mode Supported                                                                              |              |                              |                          |                        |                             |                              |                    |
| MR5           | Manufacturer ID                                                                                                                  |              |                              |                          |                        |                             |                              |                    |
|               | 1111 1111b: Micron                                                                                                               |              |                              |                          |                        |                             |                              |                    |
| MR6           | Revision ID1                                                                                                                     |              |                              |                          |                        |                             |                              |                    |
|               | 0000 0111b                                                                                                                       |              |                              |                          |                        |                             |                              |                    |
| MR8           | I/O width                                                                                                                        |              | Density                      |                          |                        |                             | Type                         |                    |
|               | OP[7:6] = 00b: x16 for 768M32, 1536M32<br>OP[7:6] = 01b: x8 for 3G32                                                             |              | OP[5:2] = 0101b: 12Gb        |                          |                        |                             | OP[1:0] = 01b: LPDDR5X SDRAM |                    |
|               |                                                                                                                                  |              |                              |                          |                        |                             |                              |                    |
| MR13          |                                                                                                                                  |              |                              |                          |                        | VRO                         |                              |                    |
|               | OP[2] = 0b: Normal operation (default)<br>1b: Output the V <sub>REF(CA)</sub> value on DQ7 and V <sub>REF(DQ)</sub> value on DQ6 |              |                              |                          |                        |                             |                              |                    |
| MR19          |                                                                                                                                  |              | WCK2DQ OSC FM                |                          |                        |                             |                              |                    |
|               | OP[5] = 1b: WCK2DQ OSC FM supported                                                                                              |              |                              |                          |                        |                             |                              |                    |



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Product-Specific Mode Register Definition

**Table 6: Mode Register Contents (Continued)**

| Mode Register | OP7                                                                                                         | OP6       | OP5    | OP4 | OP3       | OP2  | OP1    | OP0   |
|---------------|-------------------------------------------------------------------------------------------------------------|-----------|--------|-----|-----------|------|--------|-------|
| MR21          | WXS                                                                                                         |           |        |     | ODTD-CSFS | WXFS | RDCFS  | WDCFS |
|               | OP[0] = 1b: WRITE DATA COPY function supported                                                              |           |        |     |           |      |        |       |
|               | OP[1] = 1b: READ DATA COPY function supported                                                               |           |        |     |           |      |        |       |
|               | OP[2] = 1b: WRITE X function supported                                                                      |           |        |     |           |      |        |       |
|               | OP[3] = 1b: Device ODTD-CS is supported                                                                     |           |        |     |           |      |        |       |
|               | OP[7] = 1b: Data to be written can be selected with 0 and 1                                                 |           |        |     |           |      |        |       |
| MR22          | RECC                                                                                                        |           | WECC   |     |           |      |        |       |
|               | OP[5:4] = 00b: Write link ECC disabled (default)<br>01b: Write link ECC enabled (See Note 4)                |           |        |     |           |      |        |       |
|               | OP[7:6] = 00b: Read link ECC disabled (default)<br>01b: Read link ECC enabled (See Note 4)                  |           |        |     |           |      |        |       |
| MR24          | DFES                                                                                                        |           |        |     | Read DCA  |      |        |       |
|               | OP[3] = 1b: Device supports Read DCA                                                                        |           |        |     |           |      |        |       |
|               | OP[7] = 1b: Device supports DFE                                                                             |           |        |     |           |      |        |       |
| MR26          |                                                                                                             | RDQSTFS   |        |     |           |      |        |       |
|               | OP[6] = 1b: Read/write-based RDQS_t TRAINING function supported                                             |           |        |     |           |      |        |       |
| MR27          | RAAMULT                                                                                                     |           | RAAIMT |     |           |      |        | RFM   |
|               | OP[0] = 1b: RFM is required                                                                                 |           |        |     |           |      |        |       |
|               | OP[5:1] = 01110b: 112                                                                                       |           |        |     |           |      |        |       |
|               | OP[7:6] = 01b: 4X                                                                                           |           |        |     |           |      |        |       |
| MR43          |                                                                                                             | SBEC rule |        |     |           |      |        |       |
|               | OP[6] = 1b: Simultaneous SBE on each DQ byte and DMI are independently counted                              |           |        |     |           |      |        |       |
| MR57          | ARFM <sup>3</sup>                                                                                           |           |        |     | RFMSB     |      | RAADEC |       |
|               | OP[1:0] = 10b: 2 × RAAIMT                                                                                   |           |        |     |           |      |        |       |
|               | OP[3:2] = 00b: 1 = Does not support single-bank mode                                                        |           |        |     |           |      |        |       |
|               | OP[7:6] = 00b: default (01110b: 112), 01b: Level A = 01101b: 104, Level B = 01100b: 96, Level C = 01011: 88 |           |        |     |           |      |        |       |

- Notes: 1. The contents of mode registers described here reflect information specific to each die in these packages.  
 2. Refer to General LPDDR5/LPDDR5X Specification 1 for mode registers not described here.  
 3. Refer to General LPDDR5/LPDDR5X Specification 3 for feature description not described here.  
 4. Write link ECC and read link ECC are supported.



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM I<sub>DD</sub> Parameters

### I<sub>DD</sub> Parameters

Refer to I<sub>DD</sub> Specification Parameters and Test Conditions section in General LPDDR5/LPDDR5X Specifications 2 for detailed conditions.

**Table 7: I<sub>DD</sub> Parameters at 7500 Mb/s – Single Die**

| Symbol               | Supply            | x8 7500 Mb/s |      |      | x16 7500 Mb/s |      |      | Unit | Note |
|----------------------|-------------------|--------------|------|------|---------------|------|------|------|------|
|                      |                   | AIT          | AAT  | AUT  | AIT           | AAT  | AUT  |      |      |
| I <sub>DD01</sub>    | V <sub>DD1</sub>  | 3.3          | 3.3  | 3.6  | 3.3           | 3.3  | 3.6  | mA   |      |
| I <sub>DD02H</sub>   | V <sub>DD2H</sub> | 29.5         | 29.5 | 34.5 | 30.0          | 30.0 | 35.0 |      |      |
| I <sub>DD02L</sub>   | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD0Q</sub>    | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD2P1</sub>   | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD2P2H</sub>  | V <sub>DD2H</sub> | 2.2          | 2.2  | 2.7  | 2.2           | 2.2  | 2.7  |      |      |
| I <sub>DD2P2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD2PQ</sub>   | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD2PS1</sub>  | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD2PS2H</sub> | V <sub>DD2H</sub> | 2.2          | 2.2  | 2.7  | 2.2           | 2.2  | 2.7  |      |      |
| I <sub>DD2PS2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD2PSQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD2N1</sub>   | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD2N2H</sub>  | V <sub>DD2H</sub> | 16.5         | 16.5 | 20.5 | 17.0          | 17.0 | 21.0 |      |      |
| I <sub>DD2N2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD2NQ</sub>   | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD2NS1</sub>  | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD2NS2H</sub> | V <sub>DD2H</sub> | 16.5         | 16.5 | 20.5 | 17.0          | 17.0 | 21.0 |      |      |
| I <sub>DD2NS2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD2NSQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD3P1</sub>   | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD3P2H</sub>  | V <sub>DD2H</sub> | 6.0          | 6.0  | 8.0  | 6.0           | 6.0  | 8.0  |      |      |
| I <sub>DD3P2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD3PQ</sub>   | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD3PS1</sub>  | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD3PS2H</sub> | V <sub>DD2H</sub> | 6.0          | 6.0  | 8.0  | 6.0           | 6.0  | 8.0  |      |      |
| I <sub>DD3PS2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD3PSQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM I<sub>DD</sub> Parameters

**Table 7: I<sub>DD</sub> Parameters at 7500 Mb/s – Single Die**

| Symbol               | Supply            | x8 7500 Mb/s |       |       | x16 7500 Mb/s |       |       | Unit | Note |
|----------------------|-------------------|--------------|-------|-------|---------------|-------|-------|------|------|
|                      |                   | AIT          | AAT   | AUT   | AIT           | AAT   | AUT   |      |      |
| I <sub>DD3N1</sub>   | V <sub>DD1</sub>  | 1.7          | 1.7   | 2.0   | 1.7           | 1.7   | 2.0   | mA   |      |
| I <sub>DD3N2H</sub>  | V <sub>DD2H</sub> | 21.5         | 21.5  | 25.5  | 22.0          | 22.0  | 26.0  |      |      |
| I <sub>DD3N2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD3NQ</sub>   | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |
| I <sub>DD3NS1</sub>  | V <sub>DD1</sub>  | 1.7          | 1.7   | 2.0   | 1.7           | 1.7   | 2.0   | mA   |      |
| I <sub>DD3NS2H</sub> | V <sub>DD2H</sub> | 21.5         | 21.5  | 25.5  | 22.0          | 22.0  | 26.0  |      |      |
| I <sub>DD3NS2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD3NSQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |
| I <sub>DD4R1</sub>   | V <sub>DD1</sub>  | 9.0          | 9.0   | 10.0  | 11.0          | 11.0  | 12.0  | mA   | 3, 4 |
| I <sub>DD4R2H</sub>  | V <sub>DD2H</sub> | 290.0        | 295.0 | 305.0 | 430.0         | 435.0 | 445.0 |      |      |
| I <sub>DD4R2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD4RQ</sub>   | V <sub>DDQ</sub>  | 58.0         | 58.0  | 58.0  | 116.0         | 116.0 | 116.0 |      |      |
| I <sub>DD4W1</sub>   | V <sub>DD1</sub>  | 8.0          | 8.0   | 9.0   | 10.0          | 10.0  | 11.0  | mA   | 3    |
| I <sub>DD4W2H</sub>  | V <sub>DD2H</sub> | 200.0        | 205.0 | 215.0 | 280.0         | 285.0 | 295.0 |      |      |
| I <sub>DD4W2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD4WQ</sub>   | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |
| I <sub>DD51</sub>    | V <sub>DD1</sub>  | 17.0         | 17.0  | 17.0  | 17.0          | 17.0  | 17.0  | mA   |      |
| I <sub>DD52H</sub>   | V <sub>DD2H</sub> | 115.0        | 115.0 | 120.0 | 115.0         | 115.0 | 120.0 |      |      |
| I <sub>DD52L</sub>   | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD5Q</sub>    | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |
| I <sub>DD5AB1</sub>  | V <sub>DD1</sub>  | 2.5          | 2.5   | 2.8   | 2.5           | 2.5   | 2.8   | mA   |      |
| I <sub>DD5AB2H</sub> | V <sub>DD2H</sub> | 23.5         | 23.5  | 27.5  | 24.0          | 24.0  | 28.0  |      |      |
| I <sub>DD5AB2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD5ABQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |
| I <sub>DD5PB1</sub>  | V <sub>DD1</sub>  | 2.5          | 2.5   | 2.8   | 2.5           | 2.5   | 2.8   | mA   |      |
| I <sub>DD5PB2H</sub> | V <sub>DD2H</sub> | 23.5         | 23.5  | 27.5  | 24.0          | 24.0  | 28.0  |      |      |
| I <sub>DD5PB2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD5PBQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |

- Notes: 1. Published I<sub>DD</sub> values except I<sub>DD4RQ</sub> are the maximum I<sub>DD</sub> values considering the worst-case conditions of process, temperature, and voltage.
2. BG mode. DVFS and DVFSQ disabled.
3. BL = 16, DBI disabled.
4. I<sub>DD4RQ</sub> value is reference only. Typical value. Output load = 5pF; R<sub>ON</sub> = 40 ohms; T<sub>C</sub> = 25°C
5. V<sub>DD1</sub> = 1.70–1.95V; V<sub>DD2H</sub> = 1.01–1.12V; V<sub>DD2L</sub> = 0.87–0.97V; V<sub>DDQ</sub> = 0.47–0.57V
6. Notes 1 and 2 apply to entire table.



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM

### I<sub>DD</sub> Parameters

**Table 8: I<sub>DD</sub> Parameters at 8533 Mb/s – Single Die**

| Symbol               | Supply            | x8 8533 Mb/s |      |      | x16 8533 Mb/s |      |      | Unit | Note |
|----------------------|-------------------|--------------|------|------|---------------|------|------|------|------|
|                      |                   | AIT          | AAT  | AUT  | AIT           | AAT  | AUT  |      |      |
| I <sub>DD01</sub>    | V <sub>DD1</sub>  | 3.3          | 3.3  | 3.6  | 3.3           | 3.3  | 3.6  | mA   |      |
| I <sub>DD02H</sub>   | V <sub>DD2H</sub> | 29.5         | 29.5 | 34.5 | 30.0          | 30.0 | 35.0 |      |      |
| I <sub>DD02L</sub>   | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD0Q</sub>    | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD2P1</sub>   | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD2P2H</sub>  | V <sub>DD2H</sub> | 2.2          | 2.2  | 2.7  | 2.2           | 2.2  | 2.7  |      |      |
| I <sub>DD2P2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD2PQ</sub>   | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD2PS1</sub>  | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD2PS2H</sub> | V <sub>DD2H</sub> | 2.2          | 2.2  | 2.7  | 2.2           | 2.2  | 2.7  |      |      |
| I <sub>DD2PS2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD2PSQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD2N1</sub>   | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD2N2H</sub>  | V <sub>DD2H</sub> | 16.5         | 16.5 | 20.5 | 17.00         | 17.0 | 21.0 |      |      |
| I <sub>DD2N2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD2NQ</sub>   | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD2NS1</sub>  | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD2NS2H</sub> | V <sub>DD2H</sub> | 16.5         | 16.5 | 20.5 | 17.0          | 17.0 | 21.0 |      |      |
| I <sub>DD2NS2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD2NSQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD3P1</sub>   | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD3P2H</sub>  | V <sub>DD2H</sub> | 6.0          | 6.0  | 8.0  | 6.0           | 6.0  | 8.0  |      |      |
| I <sub>DD3P2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD3PQ</sub>   | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD3PS1</sub>  | V <sub>DD1</sub>  | 1.5          | 1.5  | 1.8  | 1.5           | 1.5  | 1.8  | mA   |      |
| I <sub>DD3PS2H</sub> | V <sub>DD2H</sub> | 6.0          | 6.0  | 8.0  | 6.0           | 6.0  | 8.0  |      |      |
| I <sub>DD3PS2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD3PSQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |
| I <sub>DD3N1</sub>   | V <sub>DD1</sub>  | 1.7          | 1.7  | 2.0  | 1.7           | 1.7  | 2.0  | mA   |      |
| I <sub>DD3N2H</sub>  | V <sub>DD2H</sub> | 21.5         | 21.5 | 25.5 | 22.0          | 22.0 | 26.0 |      |      |
| I <sub>DD3N2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2  | 0.2  | 0.2           | 0.2  | 0.2  |      |      |
| I <sub>DD3NQ</sub>   | V <sub>DDQ</sub>  | 0.6          | 0.6  | 0.6  | 0.6           | 0.6  | 0.6  |      |      |



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM I<sub>DD</sub> Parameters

**Table 8: I<sub>DD</sub> Parameters at 8533 Mb/s – Single Die**

| Symbol               | Supply            | x8 8533 Mb/s |       |       | x16 8533 Mb/s |       |       | Unit | Note |
|----------------------|-------------------|--------------|-------|-------|---------------|-------|-------|------|------|
|                      |                   | AIT          | AAT   | AUT   | AIT           | AAT   | AUT   |      |      |
| I <sub>DD3NS1</sub>  | V <sub>DD1</sub>  | 1.7          | 1.7   | 2.0   | 1.7           | 1.7   | 2.0   | mA   |      |
| I <sub>DD3NS2H</sub> | V <sub>DD2H</sub> | 21.5         | 21.5  | 25.5  | 22.0          | 22.0  | 26.0  |      |      |
| I <sub>DD3NS2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD3NSQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |
| I <sub>DD4R1</sub>   | V <sub>DD1</sub>  | 10.0         | 10.0  | 11.0  | 12.0          | 12.0  | 13.0  | mA   | 3, 4 |
| I <sub>DD4R2H</sub>  | V <sub>DD2H</sub> | 320.0        | 325.0 | 335.0 | 480.0         | 485.0 | 495.0 |      |      |
| I <sub>DD4R2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD4RQ</sub>   | V <sub>DDQ</sub>  | 63.0         | 63.0  | 63.0  | 126.0         | 126.0 | 126.0 |      |      |
| I <sub>DD4W1</sub>   | V <sub>DD1</sub>  | 9.0          | 9.0   | 10.0  | 11.0          | 11.0  | 12.0  | mA   | 3    |
| I <sub>DD4W2H</sub>  | V <sub>DD2H</sub> | 220.0        | 225.0 | 235.0 | 310.0         | 315.0 | 325.0 |      |      |
| I <sub>DD4W2L</sub>  | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD4WQ</sub>   | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |
| I <sub>DD51</sub>    | V <sub>DD1</sub>  | 17.0         | 17.0  | 17.0  | 17.0          | 17.0  | 17.0  | mA   |      |
| I <sub>DD52H</sub>   | V <sub>DD2H</sub> | 115.0        | 115.0 | 120.0 | 115.0         | 115.0 | 120.0 |      |      |
| I <sub>DD52L</sub>   | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD5Q</sub>    | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |
| I <sub>DD5AB1</sub>  | V <sub>DD1</sub>  | 2.5          | 2.5   | 2.8   | 2.5           | 2.5   | 2.8   | mA   |      |
| I <sub>DD5AB2H</sub> | V <sub>DD2H</sub> | 23.5         | 23.5  | 27.5  | 24.0          | 24.0  | 28.0  |      |      |
| I <sub>DD5AB2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD5ABQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |
| I <sub>DD5PB1</sub>  | V <sub>DD1</sub>  | 2.5          | 2.5   | 2.8   | 2.5           | 2.5   | 2.8   | mA   |      |
| I <sub>DD5PB2H</sub> | V <sub>DD2H</sub> | 23.5         | 23.5  | 27.5  | 24.0          | 24.0  | 28.0  |      |      |
| I <sub>DD5PB2L</sub> | V <sub>DD2L</sub> | 0.2          | 0.2   | 0.2   | 0.2           | 0.2   | 0.2   |      |      |
| I <sub>DD5PBQ</sub>  | V <sub>DDQ</sub>  | 0.6          | 0.6   | 0.6   | 0.6           | 0.6   | 0.6   |      |      |

- Notes: 1. Published I<sub>DD</sub> values except I<sub>DD4RQ</sub> are the maximum I<sub>DD</sub> values considering the worst-case conditions of process, temperature, and voltage.  
 2. BG mode. DVFS and DVFSQ disabled.  
 3. BL = 16, DBI disabled.  
 4. I<sub>DD4RQ</sub> value is reference only. Typical value. Output load = 5pF; R<sub>ON</sub> = 40 ohms; T<sub>C</sub> = 25°C  
 5. V<sub>DD1</sub> = 1.70–1.95V; V<sub>DD2H</sub> = 1.01–1.12V; V<sub>DD2L</sub> = 0.87–0.97V; V<sub>DDQ</sub> = 0.47–0.57V  
 6. Notes 1 and 2 apply to entire table.



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM I<sub>DD</sub> Parameters

**Table 9: Full-Array Power-Down Self Refresh Current – Single Die**

| Temperature | Symbol               | Supply            | Value        | Unit |
|-------------|----------------------|-------------------|--------------|------|
| 25°C        | I <sub>DD61</sub>    | V <sub>DD1</sub>  | 0.25         | mA   |
|             | I <sub>DD62H</sub>   | V <sub>DD2H</sub> | 0.45         |      |
|             | I <sub>DD62L</sub>   | V <sub>DD2L</sub> | (see note 4) |      |
|             | I <sub>DD6Q</sub>    | V <sub>DDQ</sub>  | (see note 4) |      |
|             | I <sub>DD6DS1</sub>  | V <sub>DD1</sub>  | 0.25         |      |
|             | I <sub>DD6DS2H</sub> | V <sub>DD2H</sub> | 0.45         |      |
|             | I <sub>DD6DS2L</sub> | V <sub>DD2L</sub> | (see note 4) |      |
|             | I <sub>DD6DSQ</sub>  | V <sub>DDQ</sub>  | (see note 4) |      |
| 95°C        | I <sub>DD61</sub>    | V <sub>DD1</sub>  | 3.70         | mA   |
|             | I <sub>DD62H</sub>   | V <sub>DD2H</sub> | 12.00        |      |
|             | I <sub>DD62L</sub>   | V <sub>DD2L</sub> | 0.20         |      |
|             | I <sub>DD6Q</sub>    | V <sub>DDQ</sub>  | 0.60         |      |
|             | I <sub>DD6DS1</sub>  | V <sub>DD1</sub>  | 3.70         |      |
|             | I <sub>DD6DS2H</sub> | V <sub>DD2H</sub> | 12.00        |      |
|             | I <sub>DD6DS2L</sub> | V <sub>DD2L</sub> | 0.20         |      |
|             | I <sub>DD6DSQ</sub>  | V <sub>DDQ</sub>  | 0.60         |      |
| 105°C       | I <sub>DD61</sub>    | V <sub>DD1</sub>  | 4.00         | mA   |
|             | I <sub>DD62H</sub>   | V <sub>DD2H</sub> | 17.00        |      |
|             | I <sub>DD62L</sub>   | V <sub>DD2L</sub> | 0.20         |      |
|             | I <sub>DD6Q</sub>    | V <sub>DDQ</sub>  | 0.60         |      |
|             | I <sub>DD6DS1</sub>  | V <sub>DD1</sub>  | 4.00         |      |
|             | I <sub>DD6DS2H</sub> | V <sub>DD2H</sub> | 17.00        |      |
|             | I <sub>DD6DS2L</sub> | V <sub>DD2L</sub> | 0.20         |      |
|             | I <sub>DD6DSQ</sub>  | V <sub>DDQ</sub>  | 0.60         |      |
| 125°C       | I <sub>DD61</sub>    | V <sub>DD1</sub>  | 7.00         | mA   |
|             | I <sub>DD62H</sub>   | V <sub>DD2H</sub> | 36.00        |      |
|             | I <sub>DD62L</sub>   | V <sub>DD2L</sub> | 0.20         |      |
|             | I <sub>DD6Q</sub>    | V <sub>DDQ</sub>  | 0.60         |      |
|             | I <sub>DD6DS1</sub>  | V <sub>DD1</sub>  | 7.00         |      |
|             | I <sub>DD6DS2H</sub> | V <sub>DD2H</sub> | 36.00        |      |
|             | I <sub>DD6DS2L</sub> | V <sub>DD2L</sub> | 0.20         |      |
|             | I <sub>DD6DSQ</sub>  | V <sub>DDQ</sub>  | 0.60         |      |



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM $I_{DD}$ Parameters

- Notes:
1.  $I_{DD6}25^{\circ}\text{C}$  is the typical value in the distribution with nominal  $V_{DD}$  and a reference-only value.  $I_{DD6}95/105/125^{\circ}\text{C}$  is the maximum  $I_{DD}$  guaranteed value considering the worst-case conditions of process, temperature, and voltage.
  2. DVFSC and DVFSQ disabled.
  3.  $V_{DD1} = 1.70\text{--}1.95\text{V}$ ;  $V_{DD2H} = 1.01\text{--}1.12\text{V}$ ;  $V_{DD2L} = 0.87\text{--}0.97\text{V}$ ;  $V_{DDQ} = 0.47\text{--}0.57\text{V}$
  4.  $V_{DD2L}$  and  $V_{DDQ}$  power rails are not used during power-down self refresh.



## 315b: x32 Automotive LPDDR5/LPDDR5X SDRAM Revision History

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### Revision History

#### Rev. C – 06/2022

- Add DDP

#### Rev. B – 04/2022

- Updated IDD values for Production status release
- Updated Part Number List table

#### Rev. A

- Initial preliminary release

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This data sheet contains minimum and maximum limits specified over the power supply and temperature range set forth herein. Although considered final, these specifications are subject to change, as further product development and data characterization sometimes occur.

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